NSN 5961-01-011-8314

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View Online at https://aerobasegroup.com/nsn/5961-01-011-8314 **Inclosure Material:** Metal **Overall Length:** 0.085 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 milliamperes zero-gate-voltage source current absolute **Power Rating Per Characteristic:** 0.4 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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